# **Dual 5-Input Majority Logic Gate**

The MC14530B dual five–input majority logic gate is constructed with P–channel and N–channel enhancement mode devices in a single monolithic structure. Combinational and sequential logic expressions are easily implemented with the majority logic gate, often resulting in fewer components than obtainable with the more basic gates. This device can also provide numerous logic functions by using the W and some of the logic (A thru E) inputs as control inputs.

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Capable of Driving Two Low–power TTL Loads or One Low–power Schottky TTL Load Over the Rated Temperature Range

#### MAXIMUM RATINGS\* (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage	- 0.5 to + 18.0	V
V <sub>in</sub> , V <sub>out</sub>	Input or Output Voltage (DC or Transient)	– 0.5 to V <sub>DD</sub> + 0.5	V
l <sub>in</sub> , l <sub>out</sub>	Input or Output Current (DC or Transient), per Pin	± 10	mA
PD	Power Dissipation, per Package†	500	mW
T <sub>stg</sub>	Storage Temperature	- 65 to + 150	°C
TL	Lead Temperature (8–Second Soldering)	260	°C

<sup>\*</sup> Maximum Ratings are those values beyond which damage to the device may occur. †Temperature Derating:

Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C Ceramic "L" Packages: – 12 mW/°C From 100°C To 125°C

#### **LOGIC TABLE**

INPUTS A B C D E	W	Z
For all combinations of inputs where three or	0	1
more inputs are logical "0".	1	0
For all combinations of inputs where three or	0	0
more inputs are logical "1".	1	1

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}.$ 

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.

# MC14530B



L SUFFIX CERAMIC CASE 620



P SUFFIX PLASTIC CASE 648

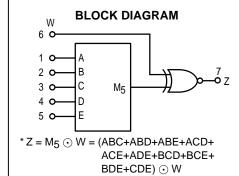


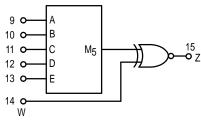
D SUFFIX SOIC CASE 751B

#### ORDERING INFORMATION

MC14XXXBCP Plastic MC14XXXBCL Ceramic MC14XXXBD SOIC

 $T_A = -55^{\circ}$  to 125°C for all packages.





- \* M<sub>5</sub> is a logical "1" if any three or more inputs are logical "1".
  - $\odot \equiv \text{Exclusive NOR} \equiv \overline{\text{Exclusive OR}}$

#### **TRUTH TABLE**

M <sub>5</sub>	W	Z
0	0	1
0	1	0
1	0	0
1	1	1

 $V_{DD} = PIN 16$  $V_{SS} = PIN 8$ 

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#### **ELECTRICAL CHARACTERISTICS** (Voltages Referenced to V<sub>SS</sub>)

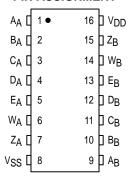
			V <sub>DD</sub>	- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Тур#	Max	Min	Max	Unit
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level	VOL	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
V <sub>in</sub> = 0 or V <sub>DD</sub>	"1" Level	VOH	5.0 10 15	4.95 9.95 14.95	_ _ _	4.95 9.95 14.95	5.0 10 15	_ _ _	4.95 9.95 14.95	_ _ _	Vdc
Input Voltage (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	"0" Level	V <sub>IL</sub>	5.0 10 15	_ _ _	1.2 2.5 3.0	_ _ _	2.25 4.50 6.75	1.25 2.5 3.0	_ _ _	1.15 2.4 2.9	Vdc
(V <sub>O</sub> = 0.5 or 4.5 Vdc) (V <sub>O</sub> = 1.0 or 9.0 Vdc) (V <sub>O</sub> = 1.5 or 13.5 Vdc)	"1" Level	VIH	5.0 10 15	3.85 7.6 12.1	_ _ _	3.75 7.5 12	2.75 5.50 8.25	_ _ _	3.75 7.5 12	_	Vdc
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)	Source	ЮН	5.0 5.0 10 15	- 3.0 - 0.64 - 1.6 - 4.2	_ _ _ _	- 2.4 - 0.51 - 1.3 - 3.4	- 4.2 - 0.88 - 2.25 - 8.8	_ _ _ _	- 1.7 - 0.36 - 0.9 - 2.4	_ _ _ _	mAdc
(V <sub>OL</sub> = 0.4 Vdc) (V <sub>OL</sub> = 0.5 Vdc) (V <sub>OL</sub> = 1.5 Vdc)	Sink	lOL	5.0 10 15	0.64 1.6 4.2	_ _ _	0.51 1.3 3.4	0.88 2.25 8.8	_ _ _	0.36 0.9 2.4	_ _ _	mAdc
Input Current		l <sub>in</sub>	15	_	± 0.1	_	±0.00001	± 0.1	_	± 1.0	μAdc
Input Capacitance (Vin = 0)		C <sub>in</sub>	_	_	_	_	5.0	7.5	_	_	pF
Quiescent Current (Per Package)		I <sub>DD</sub>	5.0 10 15	_ _	0.25 0.5 1.0	=	0.0005 0.0010 0.0015	0.25 0.5 1.0	=	7.5 15 30	μAdc
Total Supply Current**† (Dynamic plus Quiesce Per Package) (C <sub>L</sub> = 50 pF on all outp buffers switching)		lΤ	5.0 10 15			$I_{T} = (1)$	.75 μΑ/kHz) † .50 μΑ/kHz) † .25 μΑ/kHz) †	f + I <sub>DD</sub>			μAdc

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I<sub>T</sub> is in  $\mu$ A (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> – V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.002.

#### **PIN ASSIGNMENT**



<sup>\*\*</sup>The formulas given are for the typical characteristics only at 25  $^{\circ}\text{C}.$ 

<sup>\*</sup> To calculate total supply current at loads other than 50 pF:

## SWITCHING CHARACTERISTICS\* ( $C_L = 50 \text{ pF}, T_A = 25^{\circ}C$ )

Characteristic	Symbol	V <sub>DD</sub>	Min	Тур#	Max	Unit
Output Rise and Fall Time  t <sub>TLH</sub> , t <sub>THL</sub> = (1.5 ns/pF) C <sub>L</sub> + 25 ns  t <sub>TLH</sub> , t <sub>THL</sub> = (0.75 ns/pF) C <sub>L</sub> + 12.5 ns  t <sub>TLH</sub> , t <sub>THL</sub> = (0.55 ns/pF) C <sub>L</sub> + 9.5 ns	t <sub>TLH</sub> , t <sub>THL</sub>	5.0 10 15	_ _ _	100 50 40	200 100 80	ns
Propagation Delay Time A, C, W = $V_{DD}$ ; B, E = Gnd; D = Pulse Generator $t_{PLH} = (1.7 \text{ ns/pF}) C_L + 290 \text{ ns}$ $t_{PLH} = (0.66 \text{ ns/pF}) C_L + 127 \text{ ns}$ $t_{PLH} = (0.5 \text{ ns/pF}) C_L + 85 \text{ ns}$	<sup>t</sup> PLH	5.0 10 15	_ _ _	375 160 110	960 400 300	ns
$t_{PHL} = (1.7 \text{ ns/pF}) C_L + 345 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 162 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 95 \text{ ns}$	tPHL	5.0 10 15	_ _ _	430 195 120	1200 540 410	ns
A, B, C, D, E = Pulse Generator; W = V <sub>DD</sub> tp <sub>LH</sub> = (1.7 ns/pF) C <sub>L</sub> + 170 ns tp <sub>LH</sub> = (0.66 ns/pF) C <sub>L</sub> + 87 ns tp <sub>LH</sub> = (0.5 ns/pF) C <sub>L</sub> + 60 ns	<sup>t</sup> PLH	5.0 10 15	_ _ _	255 120 86	640 300 210	ns
$t_{PHL}$ = (1.7 ns/pF) $C_L$ + 195 ns $t_{PHL}$ = (0.66 ns/pF) $C_L$ + 92 ns $t_{PHL}$ = (0.5 ns/pF) $C_L$ + 75 ns	tPHL	5.0 10 15	_ _ _	280 125 100	750 330 250	ns
A, B, C, D, E = Gnd; W = Pulse Generator tpHL, tpLH = (1.7 ns/pF) C <sub>L</sub> + 145 ns tpHL, tpLH = (0.66 ns/pF) C <sub>L</sub> + 72 ns tpHL, tpLH = (0.5 ns/pF) C <sub>L</sub> + 50 ns	<sup>t</sup> PLH <sup>,</sup> <sup>t</sup> PHL	5.0 10 15	_ _ _	230 105 75	575 265 190	ns

<sup>\*</sup> The formulas given are for the typical characteristics only at 25°C.

<sup>#</sup>Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

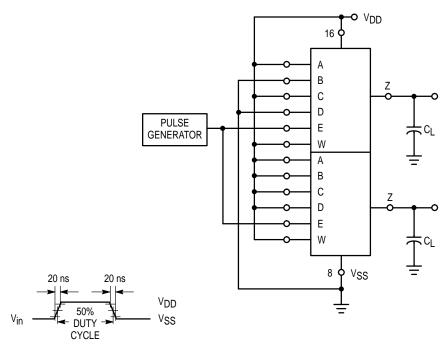
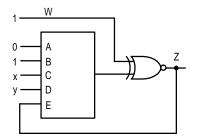


Figure 1. Power Dissipation Test Circuit and Waveform

#### **SEQUENTIAL LOGIC APPLICATIONS**

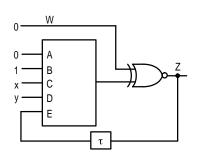


#### COINCIDENT FLIP-FLOP

**ASTABLE MULTIVIBRATOR** 

х	у	Q <sub>n+1</sub>
0	0	0
0	1	Q
0	0	Q
1	1	1

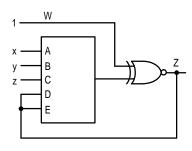
A flip-flop that will change only when both inputs agree.



x	у	Q <sub>n+1</sub>
0	0	1
0	1	2τ
1	0	2τ
1	1	1

A flip—flop with three output conditions, where the third state is in oscillation between "1" and "0". The period of oscillation is twice the delay of the gate and the feedback element.

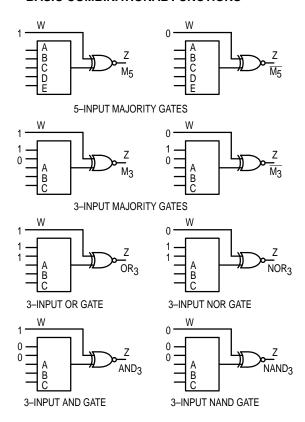
#### **COINCIDENT FLIP-FLOP**



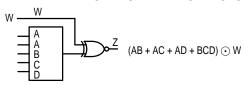
t <sub>X</sub>	у	z	Q <sub>n+1</sub>
0	0	0	0
0	0	1	Q <sub>n</sub> Q <sub>n</sub> Q <sub>n</sub>
0	1	0	Qn
0	1	1	Qn
1	0	0	Qn
1	0	1	Q <sub>n</sub> Qn
1	1	0	Qn
1	1	1	1

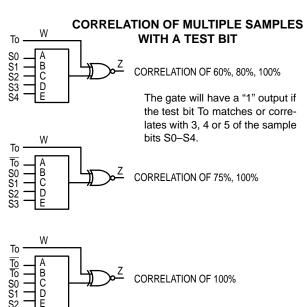
The flip–flop changes state only when all "1's" or all "0's" are entered. This configuration may be extended by cascading M5 gates to cover n–inputs where all inputs must be "1's" or "0's" before the output will change. As an example, this configuration is useful for controlling an n–stage up/down counter that is to cycle from a minimum to maximum count and back again without flipping over (from all "1's" to all "0's".)

#### **BASIC COMBINATIONAL FUNCTIONS**



# DOUBLING THE WEIGHT OF INPUT VARIABLE A BY TYING IT TO ANY TWO INPUTS

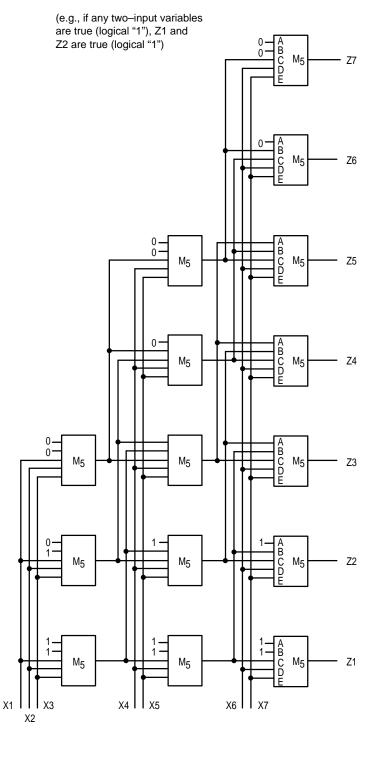




#### 5-INPUT MAJORITY LOGIC GATE APPLICATIONS

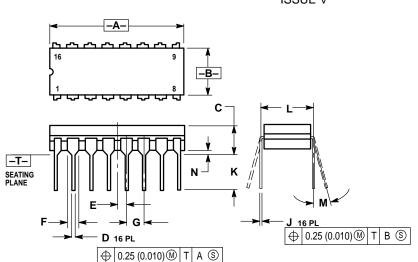
Each package labeled M<sub>5</sub> is a single majority logic gate using five inputs, A thru E, and one output Z.

 Majority Logic Gate Array yielding the symmetric function of 1 thru 7 variables true, out of 7 input variables (X1... X7)



#### **OUTLINE DIMENSIONS**

### **L SUFFIX** CERAMIC DIP PACKAGE CASE 620-10 ISSUE V



#### NOTES:

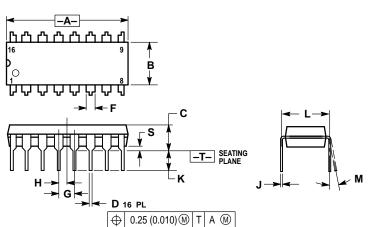
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: INCH.
  DIMENSION L TO CENTER OF LEAD WHEN
  FORMED PARALLEL.
  DIMENSION F MAY NARROW TO 0.76 (0.030)
  WHERE THE LEAD ENTERS THE CERAMIC

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.750	0.785	19.05	19.93
В	0.240	0.295	6.10	7.49
С		0.200		5.08
D	0.015	0.020	0.39	0.50
Е	0.050	BSC	1.27 BSC	
F	0.055	0.065	1.40	1.65
G	0.100	BSC	2.54	BSC
Н	0.008	0.015	0.21	0.38
K	0.125	0.170	3.18	4.31
L	0.300	0.300 BSC		BSC
М	0°	15°	0 °	15°
N	0.020	0.040	0.51	1.01

# **P SUFFIX**

PLASTIC DIP PACKAGE CASE 648-08 ISSUE R



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

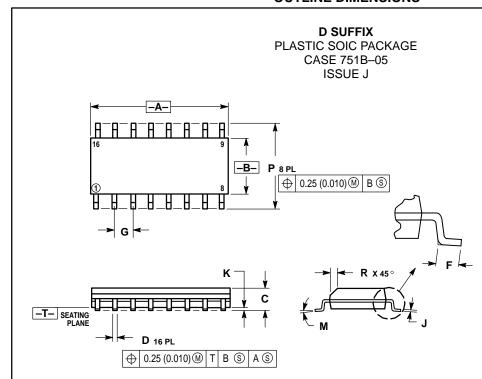
  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.

  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54	BSC
Н	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
M	0°	10°	0°	10 °
S	0.020	0.040	0.51	1.01

#### **OUTLINE DIMENSIONS**



- DIMENSIONING AND TOLERANCING PER ANSI
- CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.

  MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- PER SIDE.
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
  PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	METERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
U	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
7	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
М	0°	7°	0°	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

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MC14530B/D